



Certificate of Analysis

MRA Report #: M18-091T
Report Date: September 6, 2018
Report Type: EESstor, Inc. Samples Performance Testing
Prepared for: Mr. Ian Clifford
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715 Discovery Boulevard #107
Cedar Park, TX 78613

P.O. No: 3158-00'18 (Sample #4)

The following sample was submitted and identified on behalf of the client as:

Sample ID's: CS-18-13-4 – Densified ceramic disk, Customer ID# L-3H
Material types: Densified ceramic disk capacitor
Quantity: One per sample
Testing Period: August 21, 2018 – September 5, 2018
Objective: To independently illustrate the performance of EESstor materials across the range of operating conditions

Performed tests: **Test #1:** Capacitance & Dissipation Factor vs. Frequency (20Hz – 2MHz) @1Vrms, RT, 0V dc-bias;
Test #2: Capacitance & Dissipation Factor vs. dc-bias (up to 1000V) @1kHz, RT;
Test #3: Temperature Coefficient of Capacitance @ 1kHz, -55°C – 200°C temperature range, 0V dc-bias;
Test #4: Temperature Coefficient of Capacitance at dc-bias @ 1kHz, -55°C – 200°C temperature range, 300V dc-bias;
Test #5: Insulation Resistance @1000V, RT and 125°C;
Test #6: HALT @1000V, 180°C, 100h;
Test #7: Dielectric Breakdown Strength both at AC (up to 5000Vac) and DC (up to 6000Cdc) voltages;
Test #8: Cross-section and optical/SEM microstructure evaluation.

Summary: The results are given on the following pages as tables and plots for information only.

Customer Samples Dimensions

Sample ID#	Customer ID#	Electrode dimensions (diameter or length and width), mm	Sample thickness, mm	Electrodes area, mm ²
CS-18-13-4	#L-3H	5.69	0.55	25.42
Used equipment: Precision micrometer, 210-A. Measured uncertainty: ±0.001mm. Room temperature: 19.2°C. Relative humidity: 49.2%.				

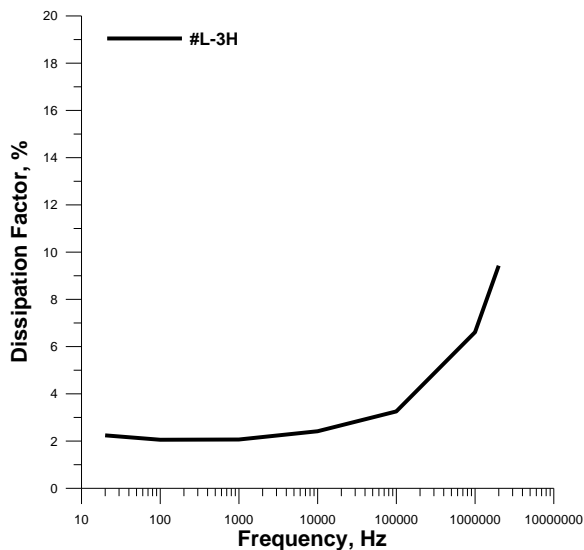
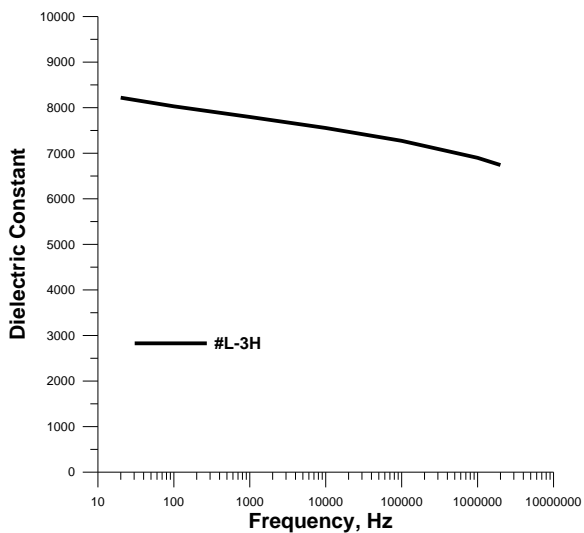
Test Results:

Test #1: Capacitance & Dissipation Factor vs. Frequency (20Hz – 2MHz)
 (@ 1Vrms, 0V dc-bias, room temperature)

Freq., Hz	CS-18-13-4 (#L-3H)	
	Cap, nF	DF, %
20	3.386	2.239
100	3.308	2.052
1,000	3.212	2.065
10,000	3.112	2.412
100,000	2.996	3.252
1,000,000	2.842	6.608
2,000,000	2.777	9.423

Used equipment: Keysight E4980A precision LCR meter.
 Measured uncertainty: C, DF $\pm 0.1\%$.
 Room temperature: 19.2°C. Relative humidity: 49.2%.

Freq., Hz	CS-18-13-4 (#L-3H)
	Estimated Dielectric Constant
20	8218
100	8029
1,000	7796
10,000	7553
100,000	7271
1,000,000	6898
2,000,000	6740

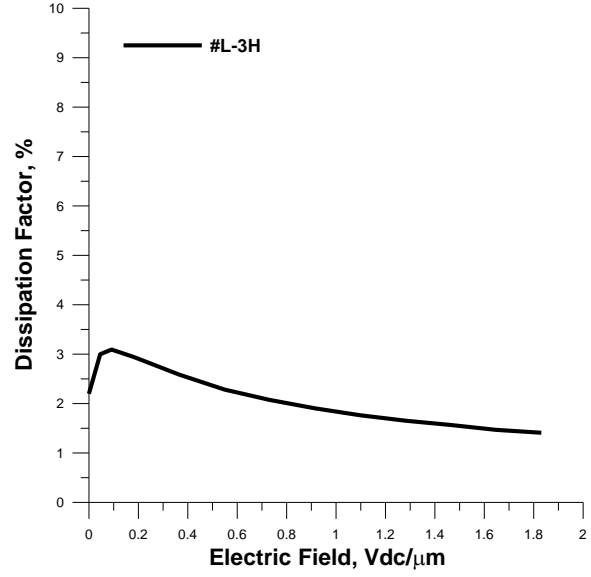
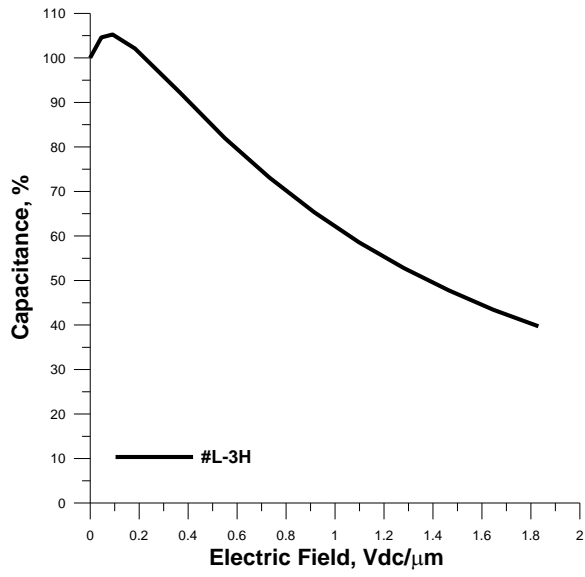


Test #2: Capacitance & Dissipation Factor vs. dc-bias (up to 1000V)
 (@ 1 kHz, room temperature)

dc-bias, V	CS-18-13-4 (#L-3H)	
	Cap, nF	DF, %
0	3.089	2.197
25	3.231	2.996
50	3.251	3.091
100	3.154	2.938
200	2.849	2.584
300	2.533	2.281
400	2.258	2.071
500	2.017	1.901
600	1.808	1.762
700	1.630	1.652
800	1.475	1.565
900	1.340	1.467
1,000	1.226	1.408

Used equipment: Keysight E4980A precision LCR meter.
 Measured uncertainty: C, DF $\pm 0.1\%$.
 Room temperature: 19.2°C. Relative humidity: 49.2%.

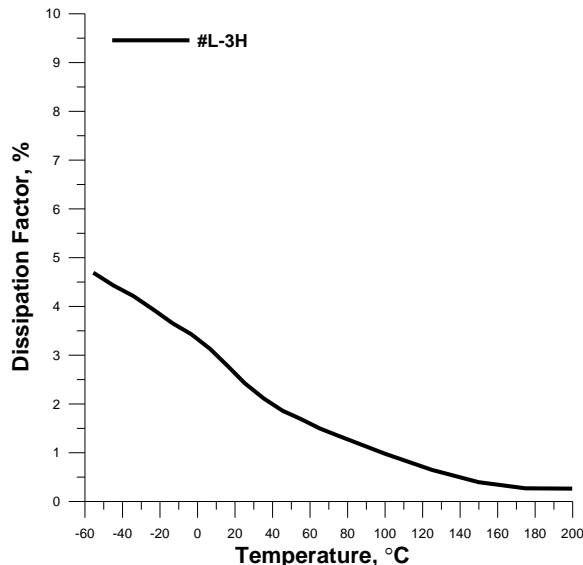
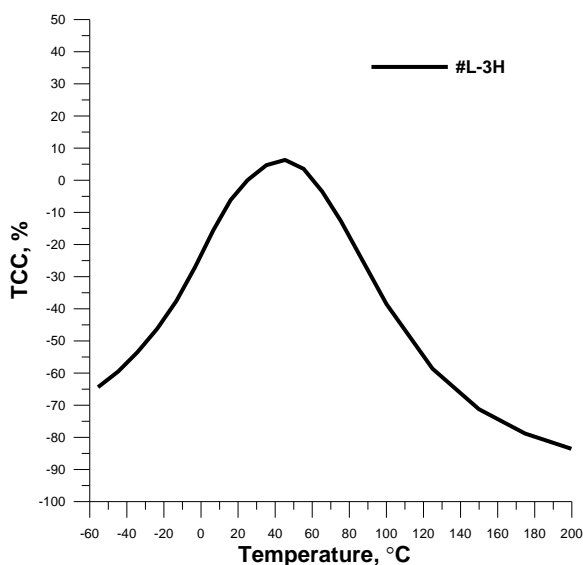
dc-bias, V	CS-18-13-4 (#L-3H)	
	E, V/ μm	Cap, %
0	0.000	100.000
25	0.046	104.597
50	0.092	105.244
100	0.183	102.104
200	0.366	92.230
300	0.549	82.001
400	0.732	73.098
500	0.916	65.296
600	1.099	58.530
700	1.282	52.768
800	1.465	47.750
900	1.648	43.380
1,000	1.831	39.689



Test #3: Temperature Coefficient of Capacitance
 (@ 1 kHz, -55°C – 200°C temperature range, 0V dc-bias)

Temp., °C	CS-18-13-4 (#L-3H)	
	Cap, %	DF, %
-55	-64.41	4.69
-45	-59.52	4.42
-35	-53.49	4.21
-25	-46.23	3.94
-15	-37.54	3.65
-5	-27.07	3.43
5	-15.42	3.12
15	-6.17	2.78
25	0.00	2.43
35	4.68	2.11
45	6.29	1.86
55	3.52	1.69
65	-3.52	1.49
75	-12.65	1.34
100	-38.60	0.98
125	-58.66	0.65
150	-71.24	0.39
175	-78.82	0.27
200	-83.57	0.26

Used equipment: HP 4278A Capacitance meter and Delta 9023 environmental chamber.
 Measured uncertainty: C, DF ±0.25%.
 Room temperature: 19.2°C. Relative humidity: 49.2%.



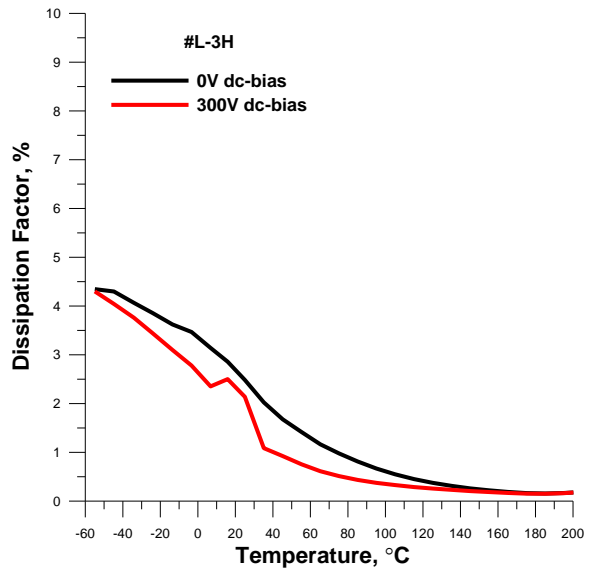
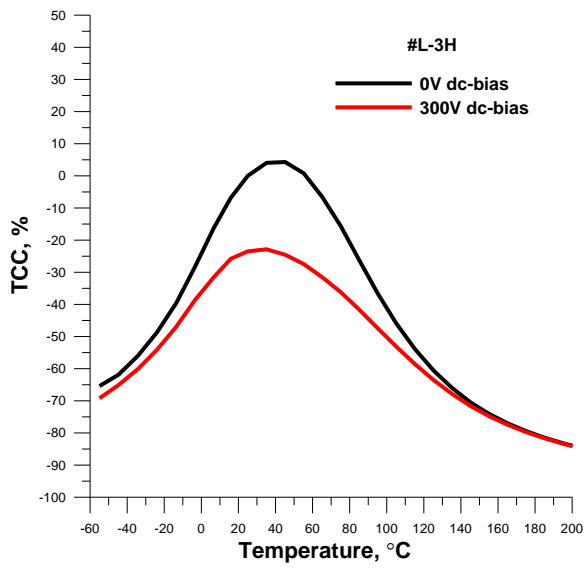
Test #4: Temperature Coefficient of Capacitance at dc-bias
 (@ 1 kHz, -55°C – 200°C temperature range, 300V dc-bias)

Temp., °C	CS-18-13-4 (#L-3H)			
	0V dc-bias		300V dc-bias	
	Cap, %	DF, %	Cap, %	DF, %
-55	-65.44	4.35	-69.23	4.30
-45	-61.91	4.30	-65.16	4.04
-35	-55.98	4.06	-60.10	3.76
-25	-48.79	3.85	-54.19	3.44
-15	-39.63	3.62	-47.00	3.10
-5	-28.24	3.47	-38.63	2.78
5	-16.18	3.14	-31.53	2.35
15	-6.86	2.86	-25.82	2.50
25	0.00	2.48	-23.51	2.14
35	4.02	2.02	-22.87	1.09
45	4.28	1.68	-24.59	0.92
55	0.76	1.42	-27.47	0.75
65	-6.65	1.16	-31.61	0.61
75	-15.69	0.98	-36.22	0.51
85	-26.27	0.81	-41.68	0.43
95	-36.64	0.67	-47.48	0.37
105	-45.95	0.55	-53.19	0.33
115	-53.95	0.45	-58.64	0.29
125	-60.61	0.37	-63.54	0.26
135	-66.03	0.31	-67.88	0.23
145	-70.50	0.26	-71.62	0.21
155	-74.08	0.22	-74.80	0.18
165	-77.04	0.19	-77.49	0.17
175	-79.47	0.16	-79.77	0.15
185	-81.50	0.15	-81.71	0.15
195	-83.22	0.16	-83.37	0.16
200	-84.00	0.18	-84.11	0.18

Used equipment: HP 4278A Capacitance meter and Delta 9023 environmental chamber.

Measured uncertainty: C, DF ±0.25%.

Room temperature: 19.2°C. Relative humidity: 49.2%.



Test #5: INSULATION RESISTANCE
 (@ 1000V, RT and 125°C)

Electrical Parameters	CS-18-13-4 (#L-3H)
Room Temperature	
IR, Ω	9.23*10 ¹²
ρ, Ω*m	4.19*10 ¹¹
R*C, MΩ*μF	28908.0
125°C	
IR, Ω	2.05*10 ¹²
ρ, Ω*m	9.31*10 ¹⁰
R*C, MΩ*μF	2569.6
Used equipment: Beckman Megaohmmeter and Delta 9023 environmental chamber. Measured uncertainty: IR ±0.25%. Room temperature: 19.2°C. Relative humidity: 49.2%.	

Test #6: Highly Accelerated Life Test
(@ 1000V, 180°C, 100h)

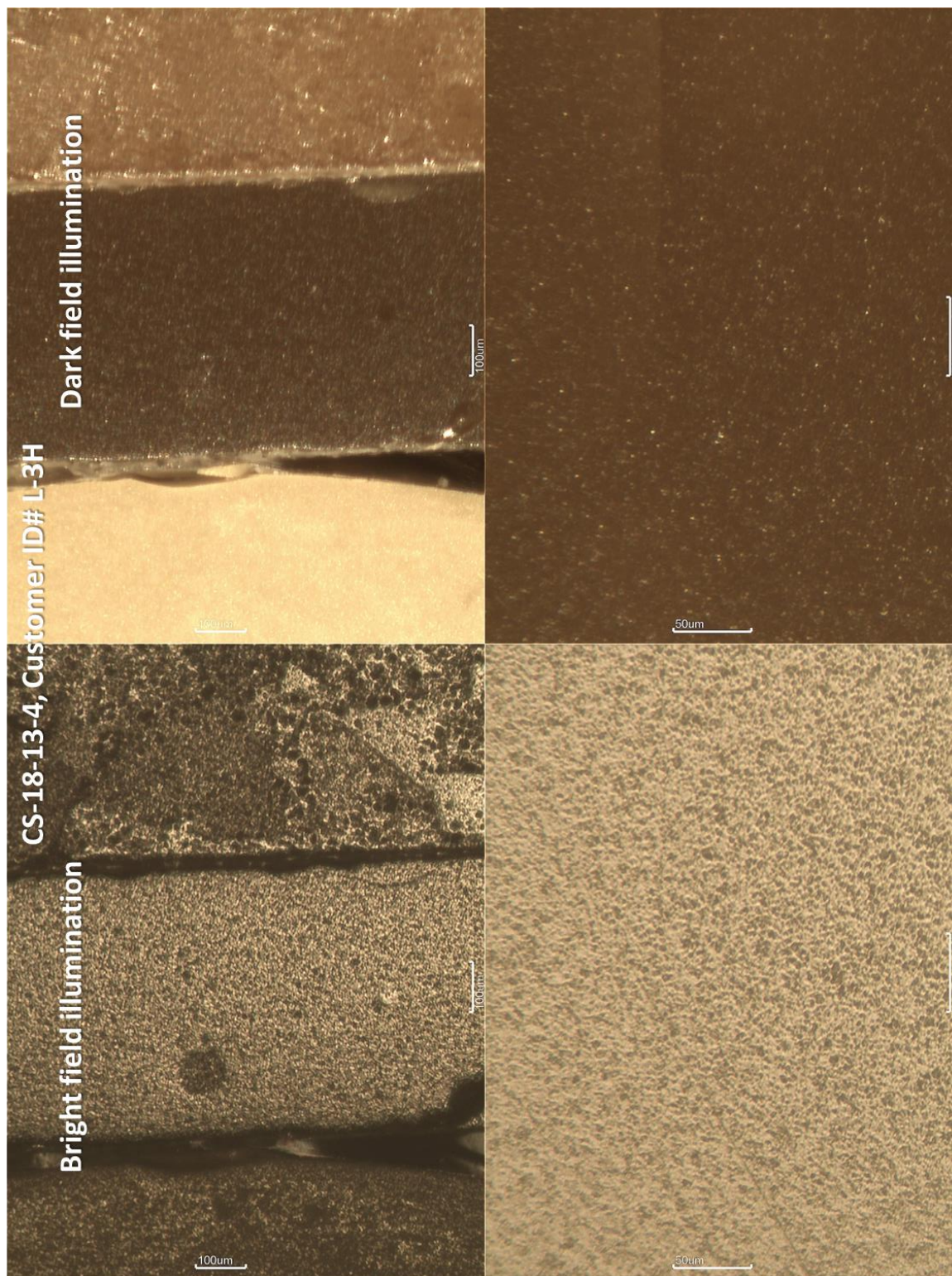
Time, h	CS-18-13-4
	(#L-3H)
	IR, Ω
2	$1.6 \cdot 10^{11}$
12	$8.9 \cdot 10^{10}$
24	$9.4 \cdot 10^{10}$
36	$9.6 \cdot 10^{10}$
48	$9.9 \cdot 10^{10}$
60	$9.9 \cdot 10^{10}$
72	$1.1 \cdot 10^{11}$
84	$1.3 \cdot 10^{11}$
96	$1.4 \cdot 10^{11}$
100	$1.5 \cdot 10^{11}$

Used equipment: Custom made HT-HALT system.
Measured uncertainty: IR $\pm 0.25\%$.
Room temperature: 19.2°C. Relative humidity: 49.2%.

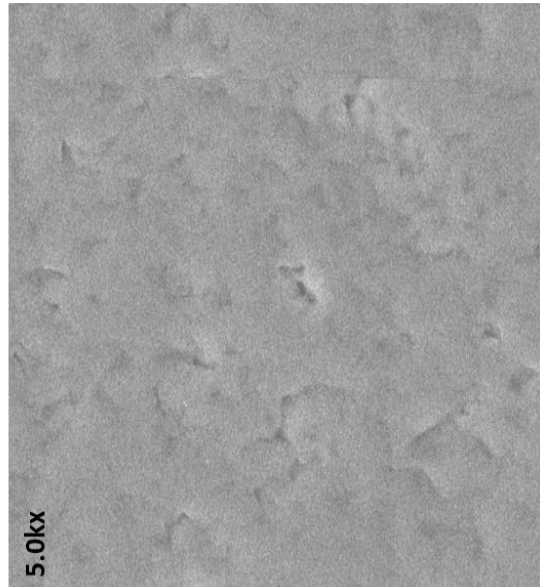
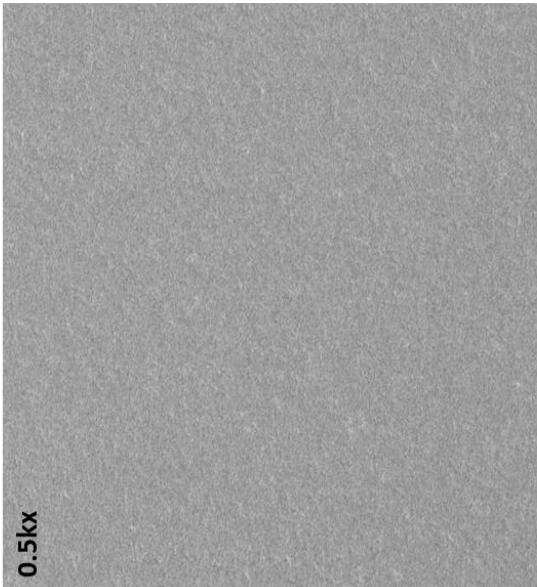
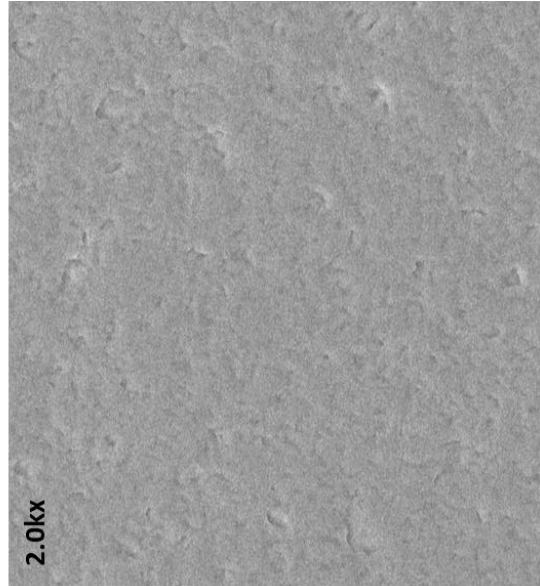
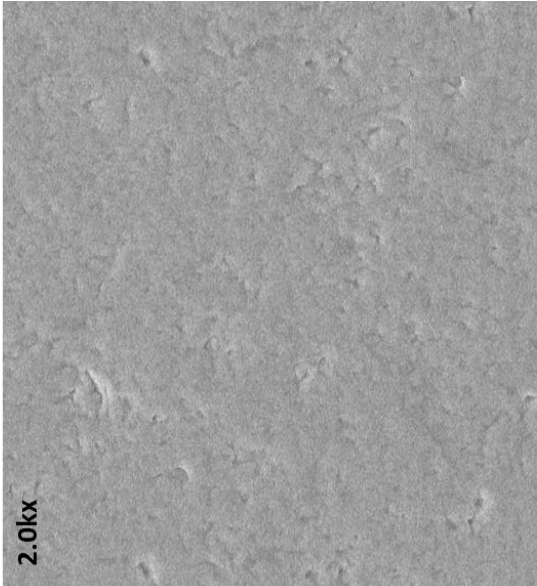
Test #7: AC and DC Dielectric Breakdown Strength
(@ Room temperature)

Electrical Parameters	CS-18-13-4 (#L-3H)
DC Dielectric Breakdown	
Ultimate Dielectric Breakdown, Vdc	>6000
Dielectric Breakdown Strength, Vdc/μm	>11.0
AC Dielectric Breakdown	
Ultimate Dielectric Breakdown, Vac	3239
Dielectric Breakdown Strength, Vac/μm	5.9
Used equipment: Chroma Sentry Plus HiPot tester 19073. Measured uncertainty $\pm 0.25\%$. Room temperature: 19.2°C. Relative humidity: 49.2%.	

Test #8: Cross-section and optical/SEM microstructure evaluation.



CS-18-13-4, Customer ID# L-3H



Test Methods

The below methods were used to perform the tests.

General

All measurement equipment was powered up at least 30 minutes prior to testing and allowed to reach a stable temperature.

Test #1: Capacitance & Dissipation Factor vs. Frequency (20Hz – 2MHz)

Electrical parameters at variable frequencies were measured using Keysight E4980A Precision LCR Meter. The measurements were performed at room temperature at 1Vrms voltage condition. Open/short correction was performed prior to measurements in order to compensate for stray admittance and residual impedance of the probe. The measurements were performed one time per sample. Dielectric constant of the densified ceramic and polymer-ceramic disks was estimated by using parallel plate capacitor model. The thickness of the disks and the area of sputtered gold electrodes were measured using a precision micrometer, while the capacitance was taken from measurements of the capacitance at variable frequencies at room temperature.

Test #2: Capacitance & Dissipation Factor vs. dc-bias (up to 1000V)

Electrical parameters at variable dc-biases were measured using Keysight E4980A Precision LCR Meter coupled with Acopian High Voltage Power Supply and ART ASY0360 HV Bias Module. The measurements were performed at room temperature at 1Vrms voltage condition. Open/short correction was performed prior to measurements in order to compensate for stray admittance and residual impedance of the probe. The measurements were performed one time per sample.

Test #3: Temperature Coefficient of Capacitance

Temperature coefficient of capacitance was measured using HP 4278A 1kHz/1MHz Capacitance Meter coupled with Rokem Scanner and Delta 9023 Environmental Chamber. The measurements were performed in the temperature range from -55°C to 200°C. Three minutes were allowed for temperature stabilization prior to measurements of capacitance and dissipation factor at each temperature steps. Open/short correction was performed prior to measurements in order to compensate for stray admittance and residual impedance of the scanner. The measurements were performed one time per sample.

Test #4: Temperature Coefficient of Capacitance at dc-bias

Temperature coefficient of capacitance at dc-bias was measured using HP 4278A 1kHz/1MHz Capacitance Meter coupled with Rokem Scanner, Sorensen DLM 300-2 Programmable dc Power Supply, ART ASY0360 HV Bias Module, and Delta 9023 Environmental Chamber. The measurements were performed in the temperature range from -55°C to 200°C. Three minutes were allowed for temperature stabilization prior to measurements of capacitance and dissipation factor at each temperature steps with and without 300V dc-bias. Open/short correction was performed prior to measurements in order to compensate for stray admittance and residual impedance of the scanner. The measurements were performed one time per sample.

Test #5: Insulation Resistance

Insulation resistance at 1000V dc-bias was measured using Beckman Megaohmmeter coupled with Delta 9023 Environmental Chamber. The measurements were performed at room temperature and at 125°C. 10 minutes were allowed for the temperature stabilization inside the chamber before each measurements. The insulation resistance was recorded after 2 minutes of dc-bias being applied. The measurements were performed one time per sample.

Test #6: Highly Accelerated Life Test (HALT)

Highly Accelerated Life Test (HALT) was performed at 180°C under the applied 1000V dc-bias using a custom made high temperature HALT system consisting of Agilent 34972A LXI Data Acquisition / Switch Unit, Acopian High Voltage Power Supply, and Across Environmental Chamber. The insulation resistance of the samples was recorded every 30 minutes for the duration of 100 hours. The measurements were performed one time per sample.


Test #7: AC and DC Dielectric Breakdown Strength

AC and DC dielectric breakdown strength measurements at room temperature were performed using Chroma Sentry Plus HiPot tester 19073. The ultimate dielectric breakdown both for AC and DC conditions was recorded during the voltage ramp up with the constant rate of 100V/sec. The samples were coated with a silicon oil to prevent surface arcing. The measurements were performed one time per sample.

Test #8: Cross-section and optical/SEM microstructure evaluation

Microstructural evaluation of the samples were performed using both optical, Unitron TMS-3906, and scanning electron, ISI-100B, microscopes. The ceramic samples were cross-sectioned and polished down to 1 micron alumina powder finish. Both bright field and dark field illumination was used in the optical microscope to reveal different features of the samples' microstructure.

Affirmation: I certify the above to be true and correct and to have witnessed the testing as described



Anton Polotai, Senior Scientist

Cc: RM, SM, JW

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